

/ Descriptions

SOT-23

NPN

Silicon NPN Digital transistor in a SOT-23 Plastic Package.

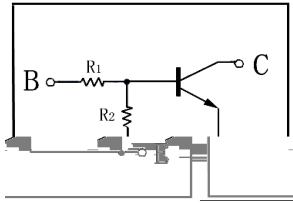
/ Features

With built-in bias resistors, simplify circuit design, reduce a quantity of parts and manufacturing process, HF Product.

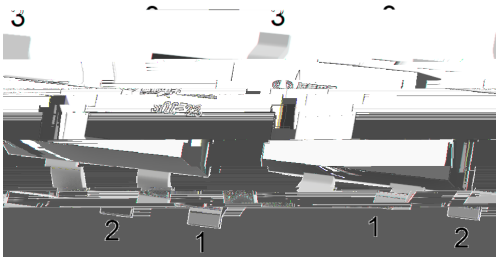
/ Applications

Switching, inverter circuit, interface circuit and driver circuit applications.

/ Equivalent Circuit



/ Pinning



PIN 1 Base

PIN 2 Emitter

PIN 3 Collector

/ h_{FE} Classifications & Marking

Marking

H26

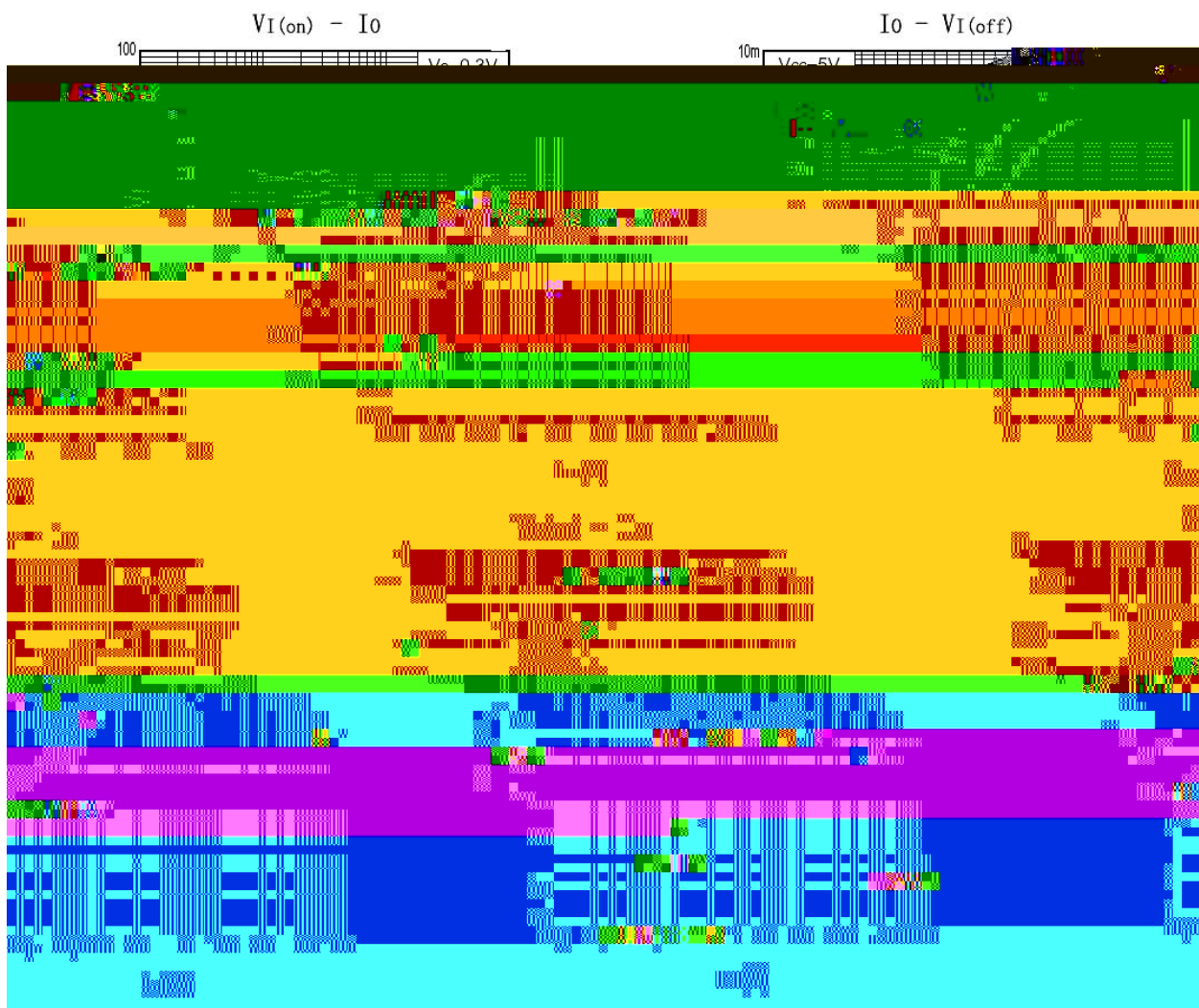
DTC144EKA

Rev.H Apr.-2025

Parameter	Symbol	Rating	Unit
Output Voltage	V_{CC}	50	V
Input Voltage	V_{IN}	40	V
		-10	V
Output Current	I_O	30	mA
Peak Collector Current	I_{CM}	100	mA
Power Dissipation	P_C	200	mW
Junction Temperature	T_j	150	
Storage Temperature Range	T_{stg}	-55 150	

Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage	$V_{I(off)}$	$V_{CC}=5.0V$ $I_O=100\mu A$	0.5			V
	$V_{I(on)}$	$V_O=0.3V$ $I_O=2mA$			3	V
Output Voltage	$V_{O(on)}$	$I_O=10mA$ $I_I=0.5mA$			0.3	V
Input Current	I_I	$V_I=5.0V$			0.18	mA

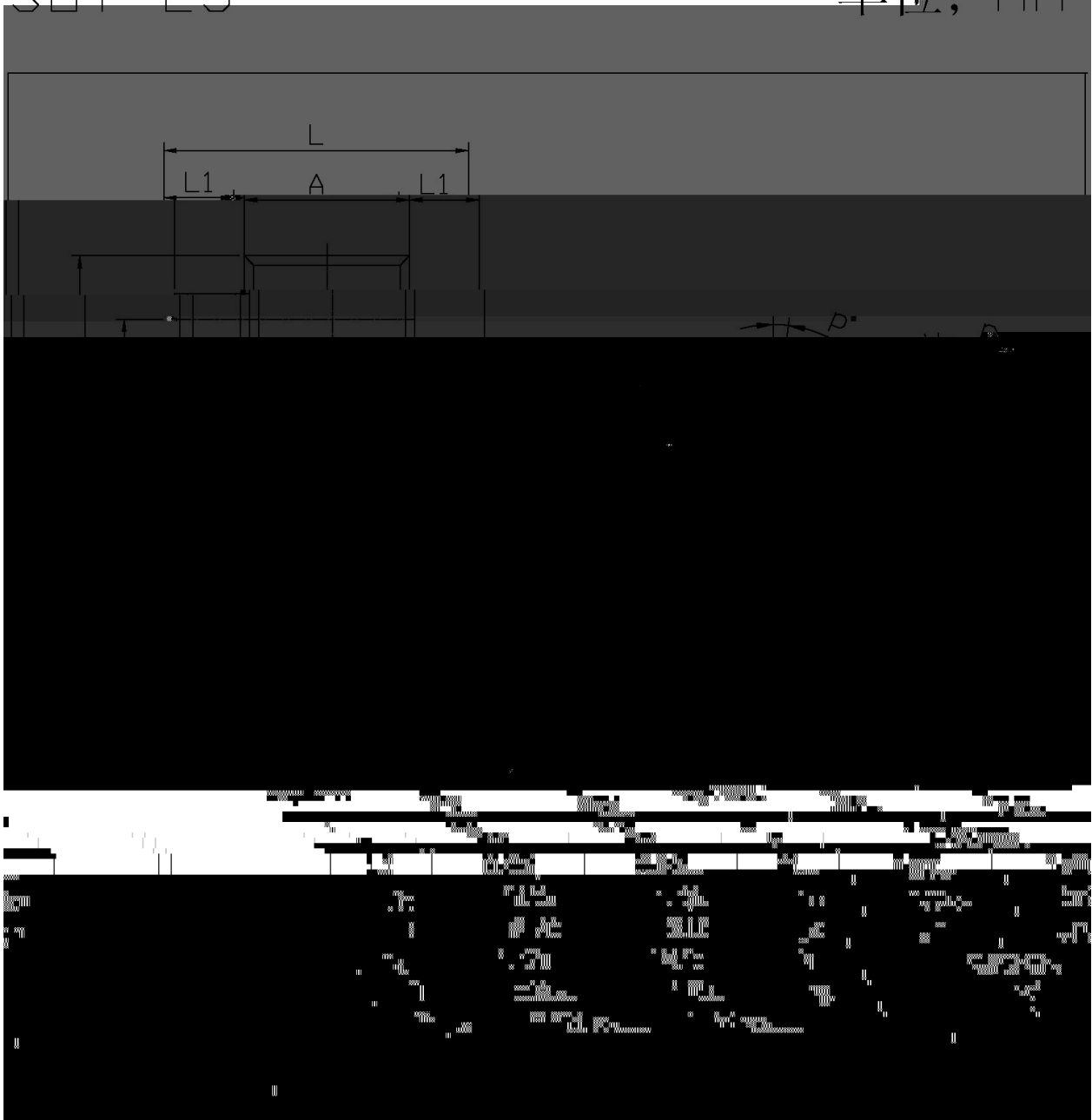
/ Electrical Characteristic Curve



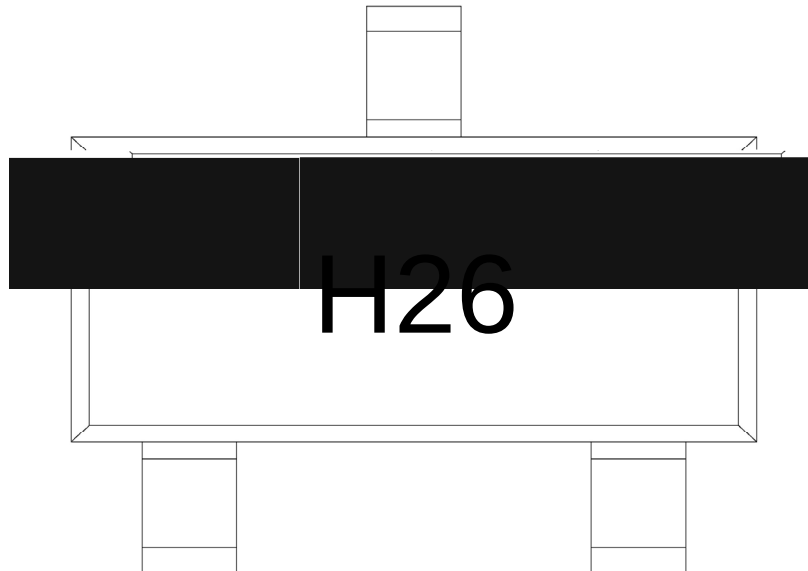
/ Package Dimensions

SOT-23

单位: mm



/ Marking Instructions



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Note:

H Company Code

26 Product Type Code

() /

- Note:
- 1

150 180

60 90sec;

2

245±5

5±0.5sec;

3

2 10 /sec.
- 1.Preheating:150~180 , Time:60~90sec.

2.Peak Temp.:245±5 , Duration:5±0.5sec.

3. Cooling Speed: 2~10 /sec.

/ Resistance to Soldering Heat Test Conditions

605±5 (/ -5.7(Packagling)24286(SPEC.())J/T7 1 Tf03.4485 32.3713 TD.0004 Tc-35.65309:6025130